

L Number	Hits	Search Text	DB	Time stamp
1	437	(257/198).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 13:58
7	506	(257/552).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 13:59
6	462	self adj (aligned alignment) and bipolar adj2 transistor and (SiGe silicon adj germanium) and (epitaxial epitaxially)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 13:59
9	64	(257/559).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 13:59
10	471	(257/593).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 13:59
11	882	(257/592).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 14:00
12	916	(257/197).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 14:00
13	358	((257/197).CCLS.) and epitaxial\$2 same base	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 14:01
14	7	((257/552).CCLS.) and (silicon adj germanium SiGe)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 14:01
15	380	((257/592).CCLS.) and epitaxial\$2 same base	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 14:01
16	223	((257/552).CCLS.) and epitaxial\$2 same base	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 14:01
17	204	((257/197).CCLS.) and self adj2 align\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/12 14:02